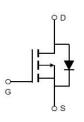
AII POWER DATA SHEET

Feature

- -60V,-25A
 R_{DS (ON)} <60m Ω @V_{GS}=-10V TYP: 52m Ω
 R_{DS (ON)} <80m Ω @V_{GS}=-4.5V TYP: 64m Ω
- Advanced Trench Technology
- Lead free product is acquired
- Excellent R _{DS (ON)} and Low Gate Charge
- Tjmax=175°C
- AEC-Q101 qualified

Application

- PWM applications
- Load Switch
- Power management



Schematic Diagram



Marking and pin assignment

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
25P06K-AU	AP25P06K-AU	TO-252	13 inch	-	2500

ABSOLUTE MAXIMUM RATINGS (T_J=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current (T _c =25℃)	lo	-25	A
Continuous Drain Current (T _c =100℃)	١ _D	-19	A
Pulsed Drain Current ⁽¹⁾	Ідм	-100	A
Single Pulsed Avalanche Energy (4)	Eas	50	mJ
Power Dissipation	PD	42	W
Thermal Resistance from Junction to Case	Rejc	3.5	°C/W
Thermal Resistance from Junction to Ambient	R _{eJA}	65	°C/W
Junction Temperature	TJ	175	°C
Storage Temperature	T _{STG}	-55~ +175	°C

MOSFET ELECTRICAL CHARACTERISTICS(TJ=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250µA	-60	-	-	V
Zero gate voltage drain current	DSS	V _{DS} =-60V, V _{GS} = 0V	-	-	1	μA
Gate-body leakage current	Igss	V_{GS} = ± 20 V, V_{DS} = 0V	-	-	±100	nA
Gate threshold voltage ⁽³⁾	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250µA	-1.0	-1.5	-2.0	V
Drain-source on-resistance ⁽³⁾		V _{GS} =-10V, I _D =-10A	-	52	60	mΩ
	RDS(on)	V _{GS} =-4.5V, I _D =-5A	-	64	80	
Dynamic characteristics						
Input Capacitance	Ciss		-	1408	-	pF
Output Capacitance	Coss		-	64	-	
Reverse Transfer Capacitance	Crss		-	47	-	
Switching characteristics						
Turn-on delay time	t _{d(on)}	V _{DD} =-30V, I _D =-10A, R _L =3Ω V _{GS} =-4.5V, R _G =4.5Ω	-	14	-	ns
Turn-on rise time	tr		-	51	-	
Turn-off delay time	t _{d(off)}		-	197	-	
Turn-off fall time	tf		-	112	-	
Total Gate Charge	Qg		-	23	-	nC
Gate-Source Charge	Qgs	VDS=-30V, ID=-10A,	-	6.5	-	
Gate-Drain Charge	Qgd	- VGS=-10V	-	3	-	
Source-Drain Diode characteristics						
Diode Forward voltage ⁽²⁾	VDS	V _{GS} =0V, I _S =-10A	-	-	-1.3	V
Diode Forward current ⁽³⁾	ls		-	-	-25	А
Body Diode Reverse Recovery Time	trr	T _J =25 $^{\circ}$, IF=-10A,di/dt=100A/us		25		ns
Body Diode Reverse Recovery Charge	Qrr	T _J =25°, IF=-10A,di/dt=100A/us		7.5		nc

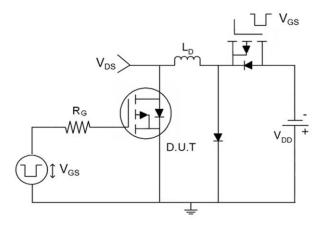
Notes:

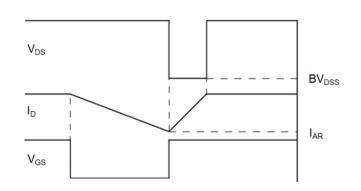
- 1. Repetitive Rating: pulse width limited by maximum junction temperature
- 2. Pulse Test: pulse width≤300µs, duty cycle≤2%
- 3. Surface Mounted on FR4 Board,t≤10 sec
- 4. EAS Condition:T_J=25 $^\circ C$,V_DD=-30V,R_G=25 Ω ,L=0.5mH



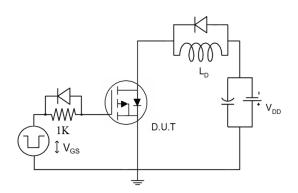
Test Circuit

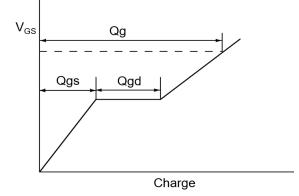
1) E_{AS} Test Circuits



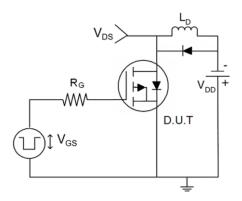


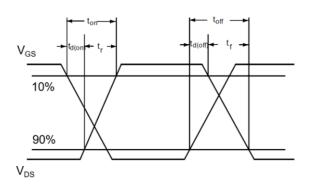
2) Gate Charge Test Circuit





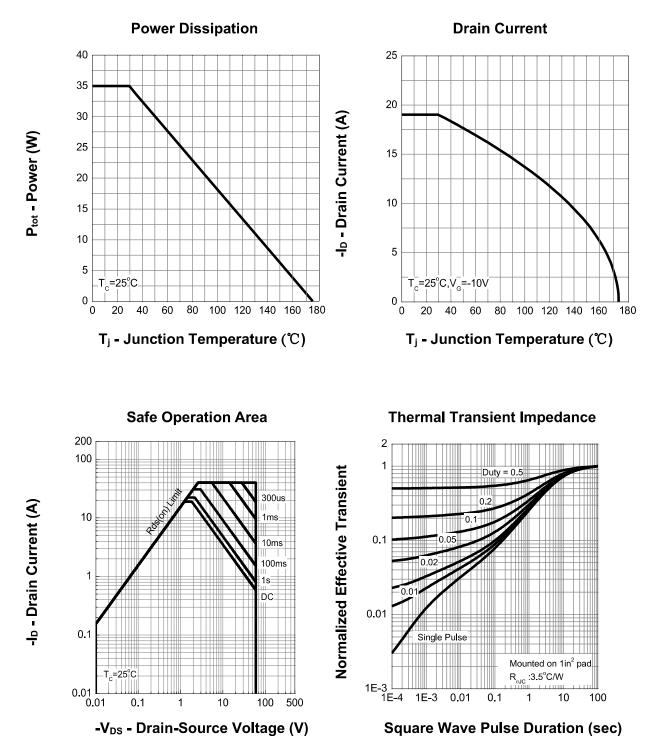
3) Switch Time Test Circuit



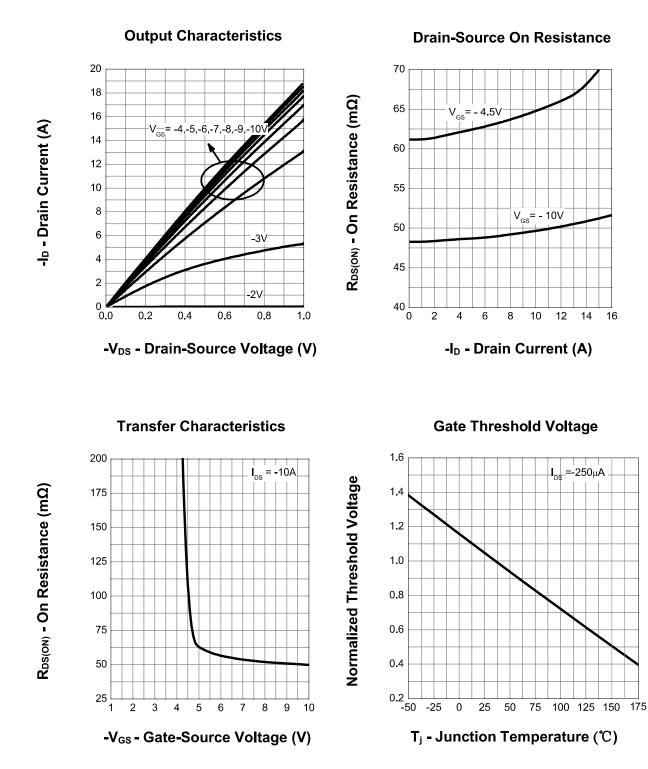


AII POWER DATA SHEET

Typical Performance Characteristics





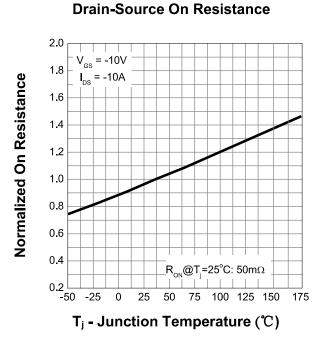


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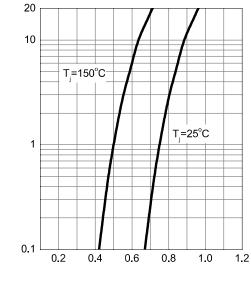
C - Capacitance (pF)

Ciss





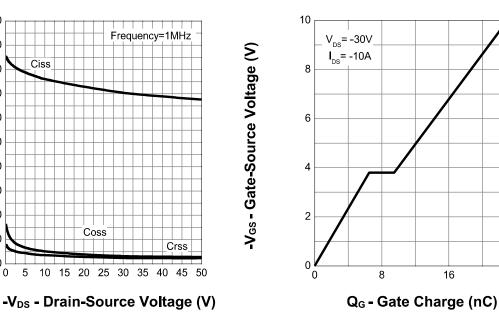
Source-Drain Diode Forward



-V_{SD} - Source-Drain Voltage (V)

Capacitance

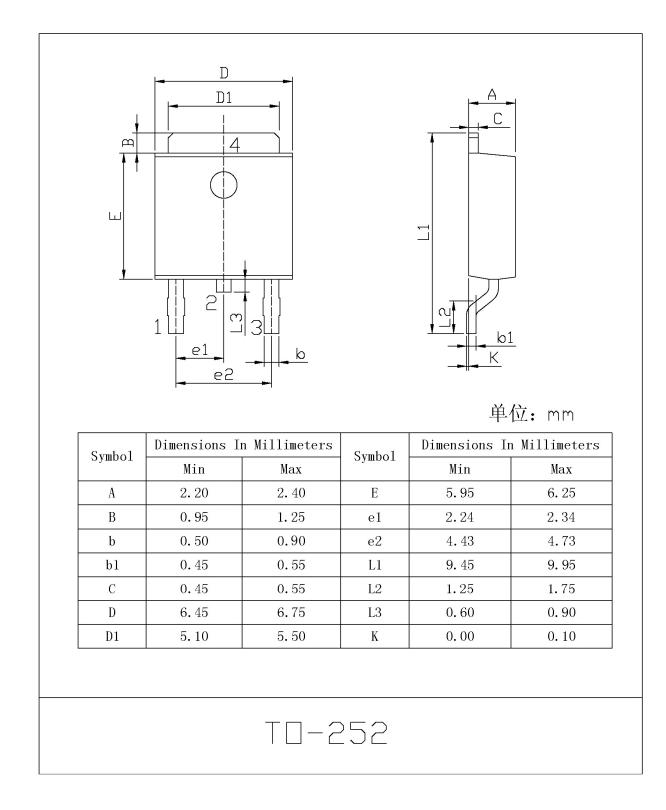




ls - Source Current (A)



TO-252 Package Information





Revision History

Revision	Release	Remark
V1.0	2022/11/30	Initial Release

Disclaimer

The information given in this document describes the independent performance of the product,but similar performance is not guaranteed under other working conditions,and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.